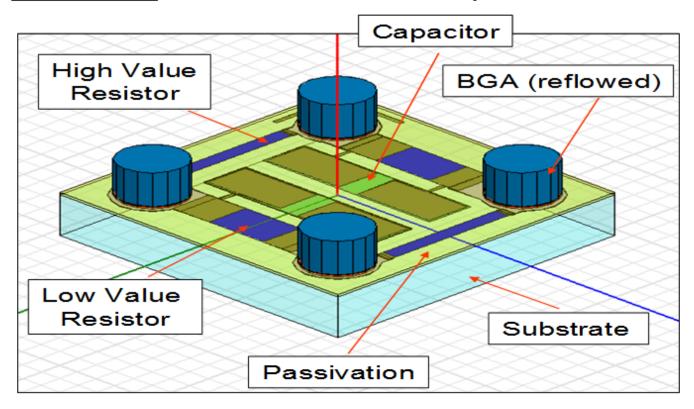
Revision 3.2

DESCRIPTION: Glass wafer based BGA RC Equalizer



DEVICE DESCRIPTION:

FEATURE	DETAIL
Size	1.5 x 1.5 mm (length x width)
Substrate	Glass wafer, 150mm diameter
Dielectric	SiON, 0.54 to 1.4µm thick, cap dependent
Specific Capacitance	100pF / mm ²
Resistor	TaN, TCR - 50 to - 150ppm
Passivation	BCB, 5µm
Under Bump Metallurgy	Plated Copper, 12µm
Termination	BGA, PbSn Eutectic or Pb free



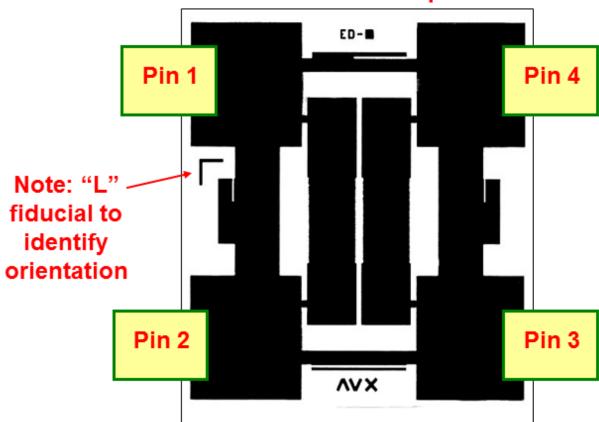
Revision 3.2

INPUT \ OUTPUT PIN ORIENTATION:

TOP VIEW LOOKING DOWN (MOUNTED PARTS): The 'L' fiducial identifies Pin 1.



Note: Pin 1 & 4 Input



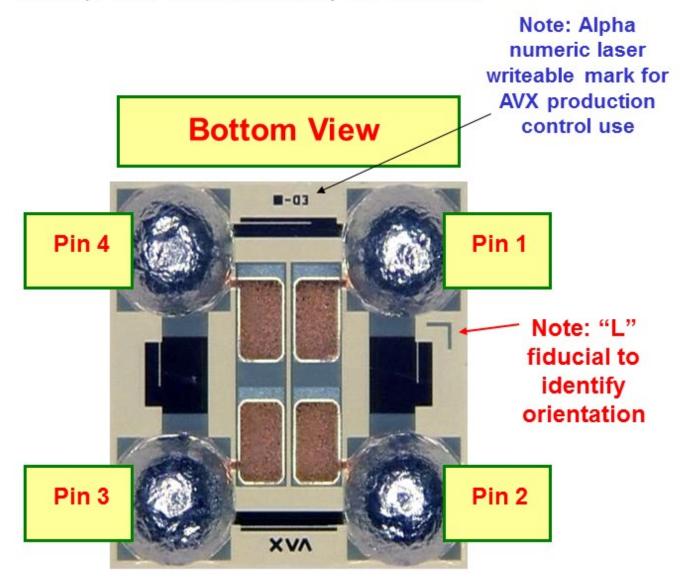
Note: Pin 2 & 3 Output



Revision 3.2

TOP VIEW (BGA TOWARDS THE OBSERVER, UNMOUNTED

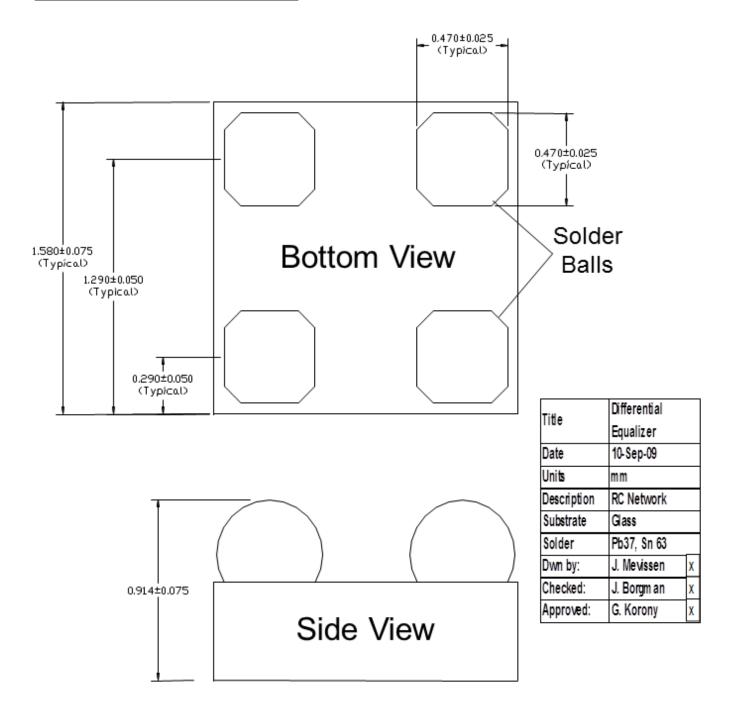
PARTS): The Pin 1 is identified by the 'L' fiducial.





Revision 3.2

EQUALIZER DIMENSIONS:





Revision 3.2

TAPE & REEL DIMENSIONS:

Part Number	Resistor / Ball Side	Orientation	Chip Tray Cavity (L x W x D)
N42042AAAAA1R	Down	Figure 1	(1.78 x 1.78 x 1.13) 8mm,4mm pitch
N42042BAAAA1R	Down	Figure 1	(1.78 x 1.78 x 1.13) 8mm,4mm pitch

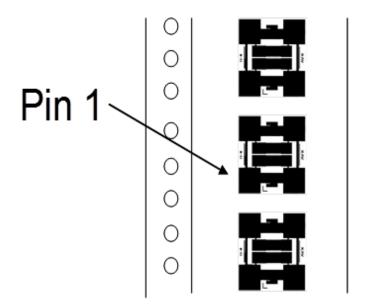


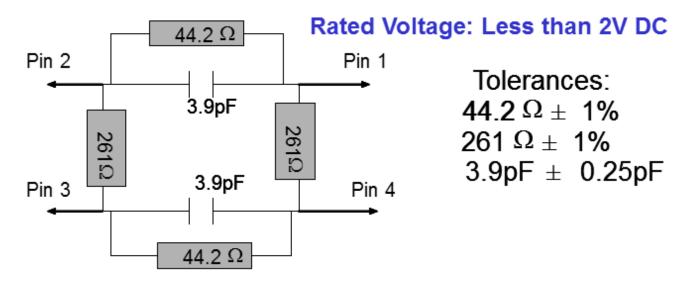
Figure 1: Tape and Reel Orientation



Revision 3.2

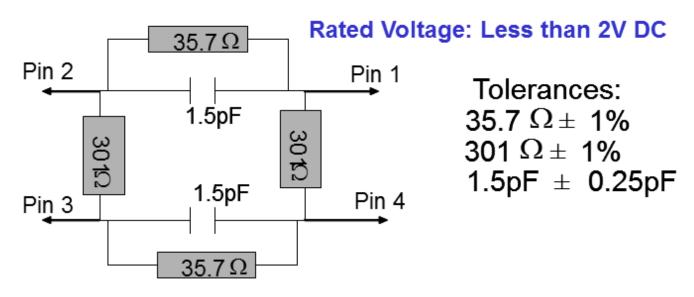
PART NUMBER: N42042AAAAA1R

Schematic 1 as specified by customer:



PART NUMBER: N42042BAAAA1R

Schematic 2 as specified by customer:





Revision 3.2

ELECTRICAL AND FUNCTIONAL REQUIREMENTS:

Test	Sample Size	
Capacitance	11 sites per wafer	
Resistance	100%	
TCR (ppm/°C)	Range - 50 to -150, 11 sites per wafer	

RELIABILITY:

Test	Method
Dielectric Voltage Breakdown	MIL-STD-883E.3008.1
Steady State Life	MIL-STD-883E.1005.8
	125°C, 1 volt DC
Steady State Humidity (85/85)	MIL-STD-202G.103B
	2 volt DC
High Temp Exposure	MIL-STD-750D.1031.5
	150°C, 100 hours
Thermal Cycle	MIL-STD-202G.107G
	1000 cycles, -5 to 75°C
Die Shear	MIL-STD-883E.2019.5
	100 μm/s shear rate; n=10



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PART NUMBER:

Position 1 = N for integrated Passive Device

Position 2 = Number of Resistors 0-9, a=10, b=11, c=12, d=13, etc. except letters O and I

Position 3 = Number of capacitors, same nomenclature as resistors

Position 4 = Number of Inductors, same nomenclature as resistors

Position 5 = Rated Voltage, 2=2V, 4=4V, Z=10V, 3=25V, 5=50V, 1-100V, V=250V, A=1000V

Position 6 = Resistor Material, 1=SiCr, 2=TaN

Position 7 = Part number designator A-Z, except letters O and I

Position 8 = Part number designator A-Z, except letters O and I

Position 9 = Part number designator A-Z, except letters O and I

Position 10 = Part number designator A-Z, except letters O and I

Position 11 = Failure rate, A=standard, G=Medical, S=Space

Position 12 = Termination type, 1=BGA eutectic 63/37, 2=BGA No Lead, 3=Wire Bond, 4=LGA, 5=Flexiterm

Position 13 = Package, R=7" reel, W=waffle pack, T = tested whole wafer, D = tested, diced wafer on film

